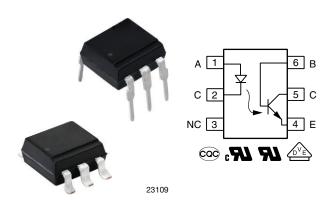


Vishay Semiconductors

Optocoupler, Phototransistor Output, With Base Connection, 300 V BV_{CEO}



LINKS TO ADDITIONAL RESOURCES













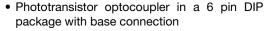
DESCRIPTION

The SFH640 has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-6 package.

It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling device is designed for signal transmission between two electrically separated circuits.

FEATURES





 Very high collector emitter breakdown voltage, BV_{CEO} = 300 V

Isolation rated voltage: 5000 V_{RMS}

- Low coupling capacitance
- High common m;ode transient immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- Telecom
- · Industrial controls
- · Battery powered equipment
- · Office machines
- Programmable controllers

AGENCY APPROVALS

- UL
- cUL
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- CQC GB4943.1-2011
- CQC GB8898-2011

ORDERING INFORMATIO	N				
S F H PART	6 4 0 - # X NUMBER CTR BIN	PACKAGE OPTION TAPE AND REEL			
AGENCY CERTIFIED / PACKAGE	CTR (%)				
AGENCY CERTIFIED / PACKAGE	AGENCY CERTIFIED / PACKAGE 10 mA				
UL, cUL	63 to 125	100 to 200			
DIP-6	SFH640-2	SFH640-3			
SMD-6, option 7	SFH640-2X007 SFH640-3X007T (1)				
VDE, UL, cUL	63 to 125 100 to 200				
SMD-6, option 9	- SFH640-3X019T				

Notes

- · Additional options may be possible, please contact sales office
- (1) Also available in tubes, do not put T on the end

Vishay Semiconductors

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT	INPUT						
Reverse voltage		V _R	6	V			
Forward current		I _F	60	mA			
Power dissipation		P _{diss}	100	mW			
OUTPUT							
Power dissipation		P _{diss}	150	mW			
Collector emitter voltage		V_{CEO}	300	V			
Collector base voltage		V_{CBO}	300	V			
Emitter base voltage		V _{EBO}	7	V			
Collector current		I _C	50	mA			
Power dissipation		P _{diss}	150	mW			
COUPLER							
Storage temperature range		T _{stg}	-55 to +150	°C			
Operating temperature range		T _{amb}	-55 to +115	°C			
Soldering temperature	t = 10 s	T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

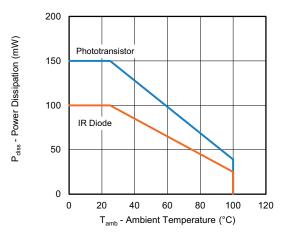


Fig. 1 - Power Dissipation vs. Ambient Temperature

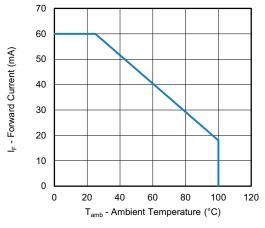


Fig. 2 - Maximum Forward Current vs. Ambient Temperature

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT					-	
Forward voltage	I _F = 10 mA	V _F	=	1.2	1.5	V
Reverse voltage	I _R = 10 μA	V _R	6	-	-	V
Reverse current	V _R = 6 V	I _R	=	0.01	10	μA
Capacitance	$V_F = 0 V, f = 1 kHz$	C _I	-	30	-	pF
OUTPUT						
Collector emitter breakdown voltage	$I_{CE} = 1 \text{ mA}, R_{BE} = 1 \text{ M}\Omega$	BV _{CEO}	300	=	=.	V
Voltage emitter base	I _{EB} = 10 μA	BV _{BEO}	7	-	-	V



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER						
Coupling capacitance	V = 0 V, f = 1 MHz	C _{IO}	-	0.6	-	pF
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 3.2 \text{ mA}$	V _{CEsat}	-	0.25	0.4	V
Collector emitter leakage current	$V_{CE} = 200 \text{ V}, R_{BE} = 1 \text{ M}\Omega$	I _{CEO}	-	1	100	nA

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	SFH640-2	CTR	63	-	125	%
I _C /I _F	$I_F = 1 \text{ mA}, V_{CE} = 10 \text{ V}$	SFH640-2	CTR	22	45	-	%
	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	SFH640-3	CTR	100	-	200	%
	$I_F = 1 \text{ mA}, V_{CE} = 10 \text{ V}$	SFH640-3	CTR	34	70	-	%

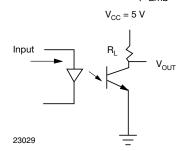
SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER TEST CONDITION SYMBOL MIN. TYP. MAX. UNIT						
Turn-on time	$I_C = 2$ mA, $R_L = 100 \Omega$, $V_{CC} = 5 V$	t _{on}	-	4	-	μs
Turn-off time	$I_C = 2$ mA, $R_L = 100 \Omega$, $V_{CC} = 5 V$	t _{off}	-	5	-	μs

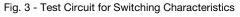
SAFETY AND INSULATION RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Climatic classification	According to IEC 68 part 1		55 / 115 / 21		
Pollution degree	According to DIN VDE 0109		2		
Comparative tracking index	Insulation group Illa	CTI	175		
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V _{ISO}	5000	V _{RMS}	
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V _{IOTM}	8000	V _{peak}	
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V _{IORM}	890	V _{peak}	
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 \text{ °C}$	R _{IO}	≥ 10 ¹²	Ω	
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω	
Output safety power		P _{SO}	700	mW	
Input safety current		I _{SI}	400	mA	
Input safety temperature		T _S	175	°C	
Creepage distance	DID 6 SMD 6		≥ 7	mm	
Clearance distance	DIP-6, SMD-6		≥ 7	mm	
Insulation thickness		DTI	≥ 0.4	mm	

Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)





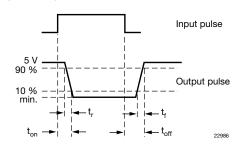


Fig. 4 - Parameter and Limit Definition





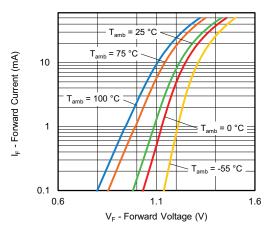


Fig. 5 - Forward Current vs. Forward Voltage

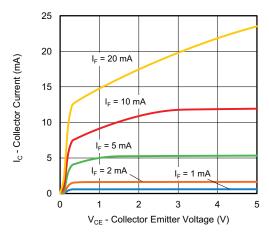


Fig. 6 - Collector Current vs. Collector Emitter Voltage (non-saturated)

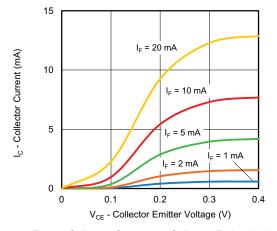


Fig. 7 - Collector Current vs. Collector Emitter Voltage (saturated)

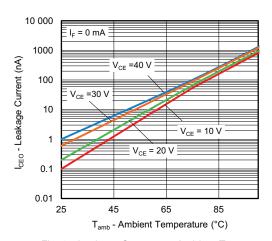


Fig. 8 - Leakage Current vs. Ambient Temperature

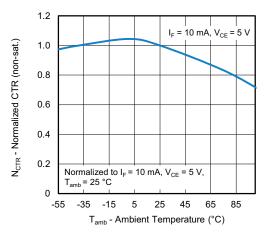


Fig. 9 - Normalized CTR vs. Ambient Temperature (non-saturated)

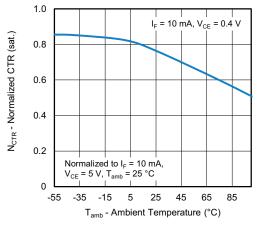


Fig. 10 - Normalized CTR vs. Ambient Temperature (saturated)



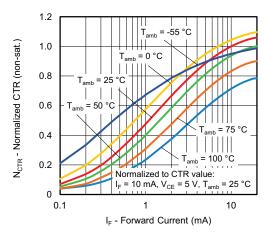


Fig. 11 - Normalized CTR (non-saturated) vs. Forward Current

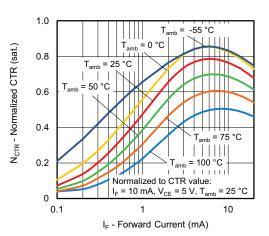


Fig. 12 - Normalized CTR (saturated) vs. Forward Current

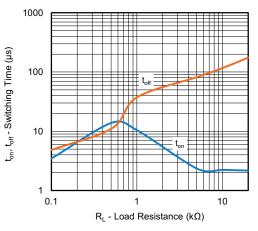


Fig. 13 - Switching Time vs. Load Resistance

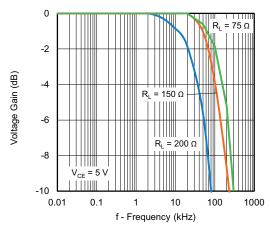
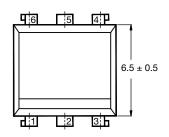


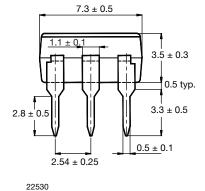
Fig. 14 - Voltage Gain vs. Frequency

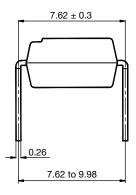


PACKAGE DIMENSIONS in millimeters

6 Pin Package

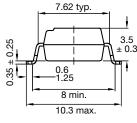


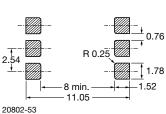


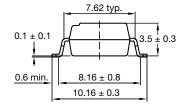


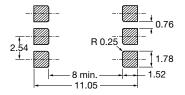
Option 7

Option 9









PACKAGE MARKING

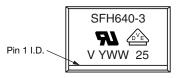


Fig. 15 - Example of SFH640

Notes

- "YWW" is the date code marking (Y = year code, WW = week code)
- VDE logo is only marked on VDE option parts
- Tape and reel suffix (T) is not part of the package marking



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PACKAGING INFORMATION

DEVICES PER TUBE					
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX		
DIP-6	50	40	2000		
SMD-6	50	40	2000		

DIP-6

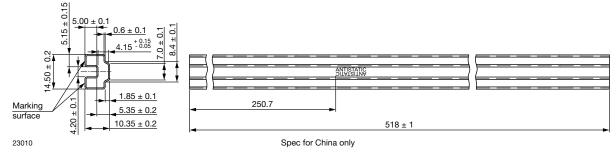


Fig. 16 - DIP-6

SMD-6

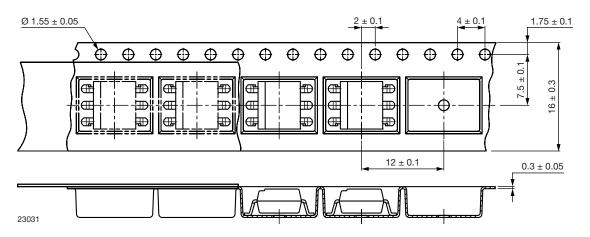


Fig. 17 - SMD-6

Reel

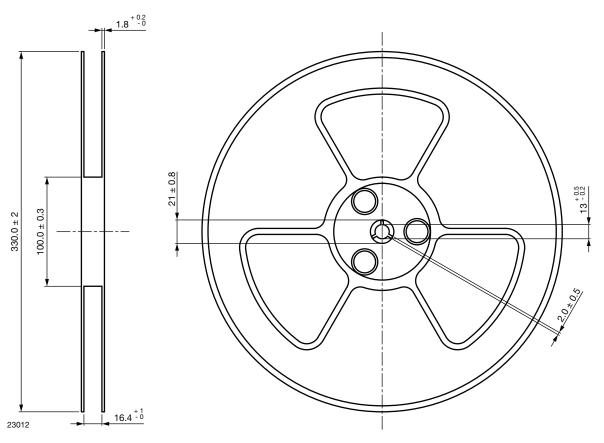


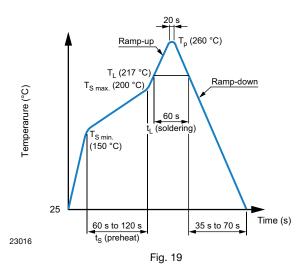
Fig. 18 - Tape and Reel Shipping Medium

SOLDER PROFILES

IR Reflow Soldering (JEDEC® J-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

PROFILE ITEM	CONDITIONS
Preheat	
- Temperature minimum (T _{S min.})	150 °C
- Temperature maximum (T _{S max.})	200 °C
- Time (min. to max.) (t _S)	90 s ± 30 s
Soldering zone	
- Temperature (T _L)	217 °C
- Time (t _L)	60 s
Peak temperature (Tp)	260 °C
Ramp-up rate	3 °C/s max.
Ramp-down rate	3 °C/s to 6 °C/s





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Wave Soldering (JEDEC JESD22-A111 compliant)

One time soldering is recommended within the condition of

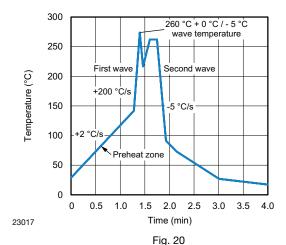
temperature.

Temperature: 260 °C + 0 °C / - 5 °C

Time: 10 s

Preheat temperature: 25 °C to 140 °C

Preheat time: 30 s to 80 s



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Hand Soldering by Soldering Iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature: 380 °C + 0 °C / - 5 °C

Time: 3 s max.



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